Panasonic FC8V33030L

# FC8V33030L

### **Dual N-channel MOSFET**

For DC-DC Converter

### ■ Features

- Low drain-source ON resistance:RDS(on)typ. = 22 m $\Omega$  (VGS = 4.5 V)
- High-speed switching :Qg = 3.8 nC
- Halogen-free / RoHS compliant

(EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)

- Marking Symbol:6A
- Basic Part Number

Dual Nch MOS 33 V (Individual)

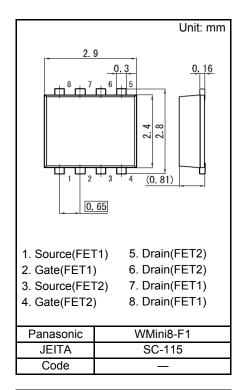
#### ■ Packaging

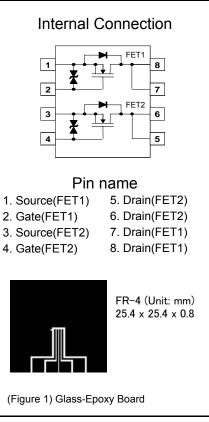
FC8V33030L Embossed type (Thermo-compression sealing): 3 000 pcs / reel (standard)

### ■ Absolute Maximum Ratings Ta = 25 °C

	Parameter	Symbol	Rating	Unit	
FET1 FET2	Drain-source Voltage	VDS	33	V	
	Gate-source Voltage	VGS	±20	V	
	Drain Current (Steady State) *1	ID	6.5		
	Drain Current (t=10s) *1	טו	8		
	Drain Current (Pulsed) *1,2	IDp	26	Α	
	Source Current (Pulsed)	ISp	6.5		
	(Body Diode) *1,2	(BD)	0.5		
Overall	Power Dissipation (Steady State) *1	PD 1		W	
	Power Dissination (t=10s) *1	רט	1.5	VV	
	Channel Temperature	Tch	150	°C	
	Storage Temperature Range	Tstg	-55 to +150	°C	

Note: \*1 Device mounted on a glass-epoxy board (See Figure 1)





<sup>\*2</sup> Pulse test: Ensure that the channel temperature does not exceed 150 °C.

Panasonic FC8V33030L

### ■ Electrical Characteristics Ta = 25 °C ± 3 °C

### Static Characteristics

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Drain-source Breakdown Voltage	VDSS	ID = 1 mA, VGS = 0 V	33			V
Zero Gate Voltage Drain Current	IDSS	VDS = 33 V, VGS = 0 V			10	μΑ
Gate-source Leakage Current	IGSS	VGS = ±16 V, VDS = 0 V			±10	μA
Gate-source Threshold Voltage	Vth	ID = 0.48 mA, VDS = 10 V	1		2.5	V
Drain-source On-state Resistance *1	RDS(on)1	ID = 3.3 A, VGS = 10 V		15	20	mΩ
Diain-Source On-State Resistance	RDS(on)2	ID = 3.3 A, VGS = 4.5 V		22	35	

Note \*1 Pulse test: Ensure that the channel temperature does not exceed 150 °C

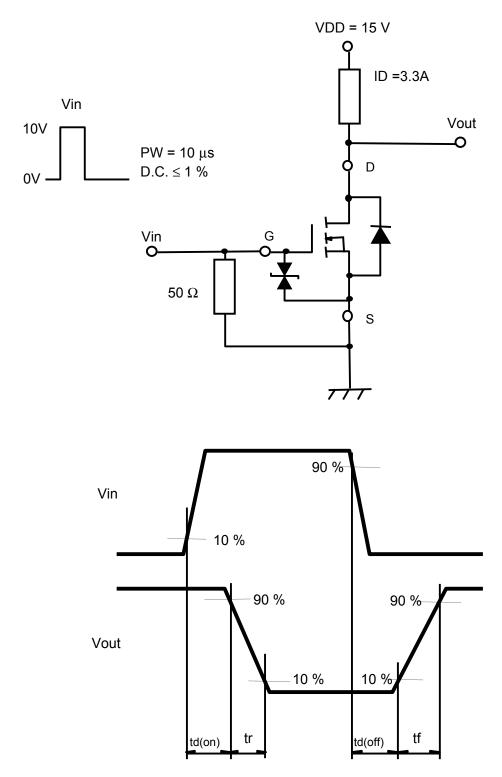
**Dynamic Characteristics** 

Input Capacitance	Ciss	VDS = 10 V VCS = 0 V	360	
Output Capacitance	Coss	VDS = 10 V, VGS = 0 V, f = 1 MHz	70	pF
Reverse Transfer Capacitance	Crss	- I - I WITZ	50	
Turn-On Delay Time	td(on)	VDD = 15 V, VGS = 0 to 10 V	8	
Rise Time	tr	ID = 3.3 A (Figure 2)	3	20
Turn-Off Delay Time	td(off)	VDD = 15 V, VGS = 10 to 0 V	24	ns
Fall Time	tf	ID = 3.3 A (Figure 2)	9	
Total Gate Charge	Qg	Qg VDD = 15 V, VGS = 0 to 4.5 V,		
Gate-source Charge	Qgs	ID = 6.5 A	1.4	nC
Gate-drain Charge	Qgd	7 ID - 0.5 A	1.6	

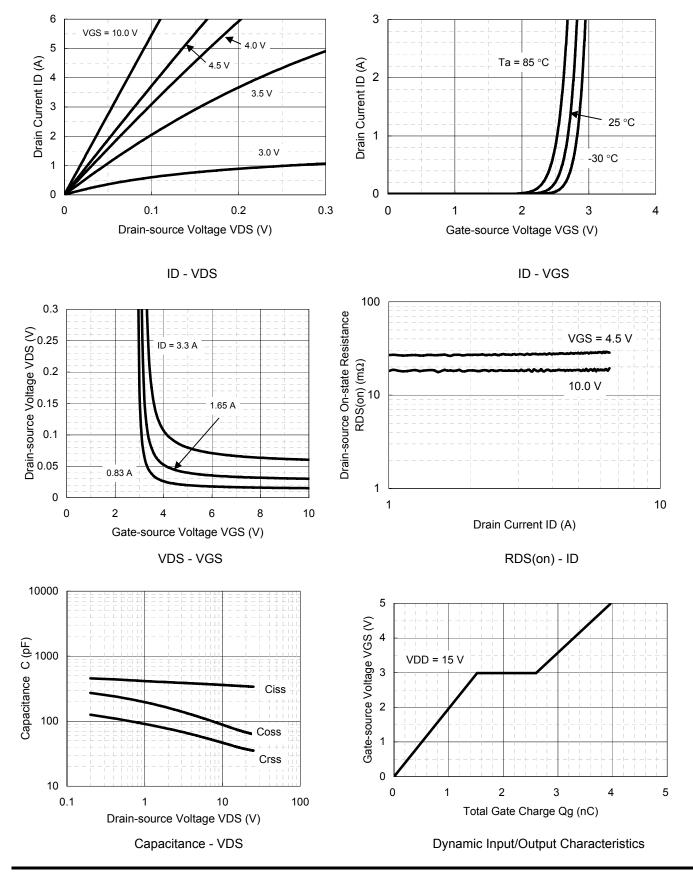
Body Diode Characteristic							
Diode Forward Voltage *1	VSD	IS = 3.3 A, VGS = 0 V		0.8	1.2	V	

Note \*1 Pulse test: Ensure that the channel temperature does not exceed 150 °C

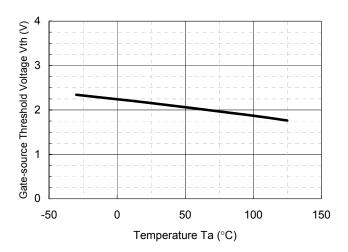
Ver. BED 2

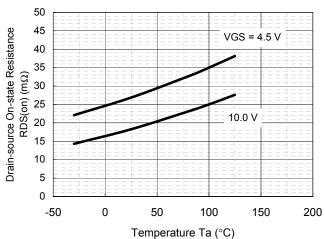


(Figure 2) Measuremet circuit for Turn-On Delay Time/Rise Time/Turn-Off Delay Time/Fall Time



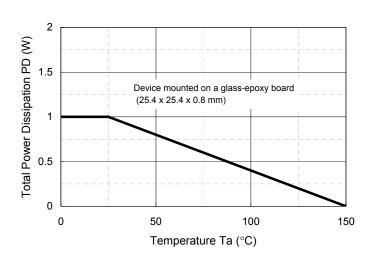
Ver. BED 4



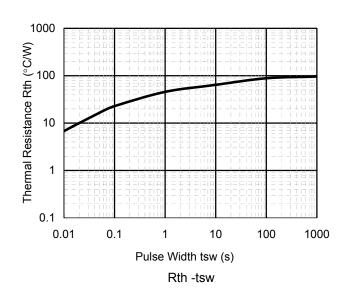


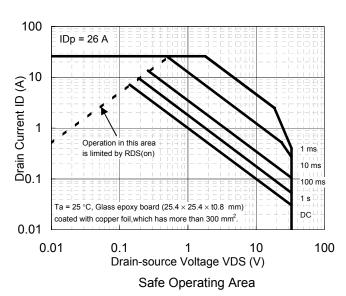
Vth - Ta

RDS(on) - Ta



PD - Ta

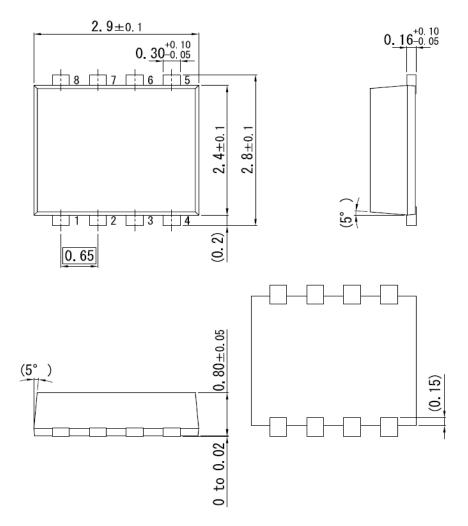




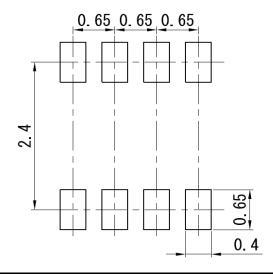
Ver. BED 5

WMini8-F1





### ■ Land Pattern (Reference) (Unit: mm)



Ver. BED

6

# Request for your special attention and precautions in using the technical information and semiconductors described in this book

- (1) If any of the products or technical information described in this book is to be exported or provided to non-residents, the laws and regulations of the exporting country, especially, those with regard to security export control, must be observed.
- (2) The technical information described in this book is intended only to show the main characteristics and application circuit examples of the products. No license is granted in and to any intellectual property right or other right owned by Panasonic Corporation or any other company. Therefore, no responsibility is assumed by our company as to the infringement upon any such right owned by any other company which may arise as a result of the use of technical information described in this book.
- (3) The products described in this book are intended to be used for general applications (such as office equipment, communications equipment, measuring instruments and household appliances), or for specific applications as expressly stated in this book.

  Consult our sales staff in advance for information on the following applications:
  - Special applications (such as for airplanes, aerospace, automotive equipment, traffic signaling equipment, combustion equipment, life support systems and safety devices) in which exceptional quality and reliability are required, or if the failure or malfunction of the products may directly jeopardize life or harm the human body.
  - It is to be understood that our company shall not be held responsible for any damage incurred as a result of or in connection with your using the products described in this book for any special application, unless our company agrees to your using the products in this book for any special application.
- (4) The products and product specifications described in this book are subject to change without notice for modification and/or improvement. At the final stage of your design, purchasing, or use of the products, therefore, ask for the most up-to-date Product Standards in advance to make sure that the latest specifications satisfy your requirements.
- (5) When designing your equipment, comply with the range of absolute maximum rating and the guaranteed operating conditions (operating power supply voltage and operating environment etc.). Especially, please be careful not to exceed the range of absolute maximum rating on the transient state, such as power-on, power-off and mode-switching. Otherwise, we will not be liable for any defect which may arise later in your equipment.
  - Even when the products are used within the guaranteed values, take into the consideration of incidence of break down and failure mode, possible to occur to semiconductor products. Measures on the systems such as redundant design, arresting the spread of fire or preventing glitch are recommended in order to prevent physical injury, fire, social damages, for example, by using the products.
- (6) Comply with the instructions for use in order to prevent breakdown and characteristics change due to external factors (ESD, EOS, thermal stress and mechanical stress) at the time of handling, mounting or at customer's process. When using products for which damp-proof packing is required, satisfy the conditions, such as shelf life and the elapsed time since first opening the packages.
- (7) This book may be not reprinted or reproduced whether wholly or partially, without the prior written permission of our company.

20100202

### **ПОСТАВКА** ЭЛЕКТРОННЫХ КОМПОНЕНТОВ

многоканальный

Общество с ограниченной ответственностью «МосЧип» ИНН 7719860671 / КПП 771901001 Адрес: 105318, г.Москва, ул.Щербаковская д.3, офис 1107

# Данный компонент на территории Российской Федерации Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

### http://moschip.ru/get-element

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

### Офис по работе с юридическими лицами:

105318, г. Москва, ул. Щербаковская д. 3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru moschip.ru\_6 moschip.ru\_4 moschip.ru\_9